NSN 5961-00-478-7617

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-478-7617 **Inclosure Material:** Metal **Overall Length:** 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.865 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to base voltage, dc and 300.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 96214-535247 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf

N/a

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

NSN 5961-00-478-7617

Transistor - Page 2 of 2



	1	:.	~	84				
ι	JN	IT	UΤ	IVI	ea	Sι	ire:	•

--

Demilitarization:

No

Fiig:

A110a0